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(54) **SEMICONDUCTOR PACKAGE WITH
CONDUCTIVE HEAT SPREADER**

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7, 2006.

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USPC 257/13, 698, 675, 690, 737, E21.575,
257/666, E21.6

See application file for complete search history.

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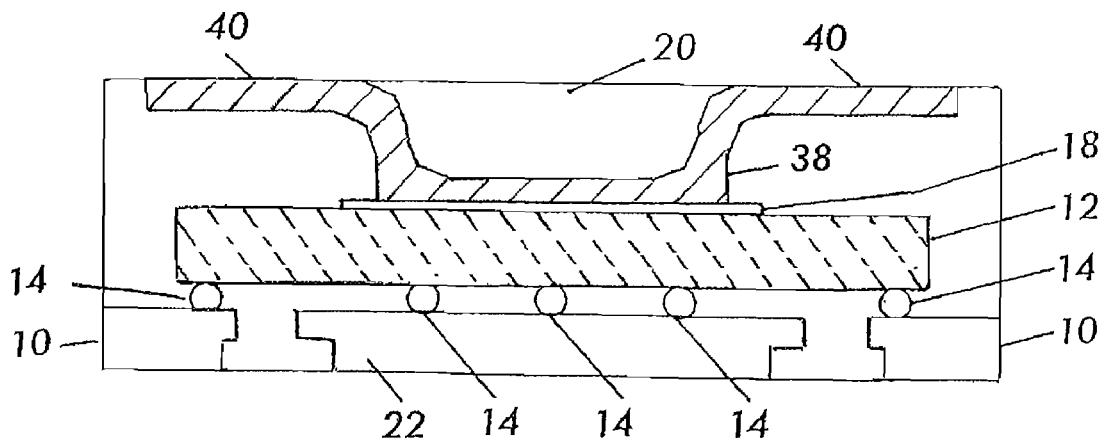
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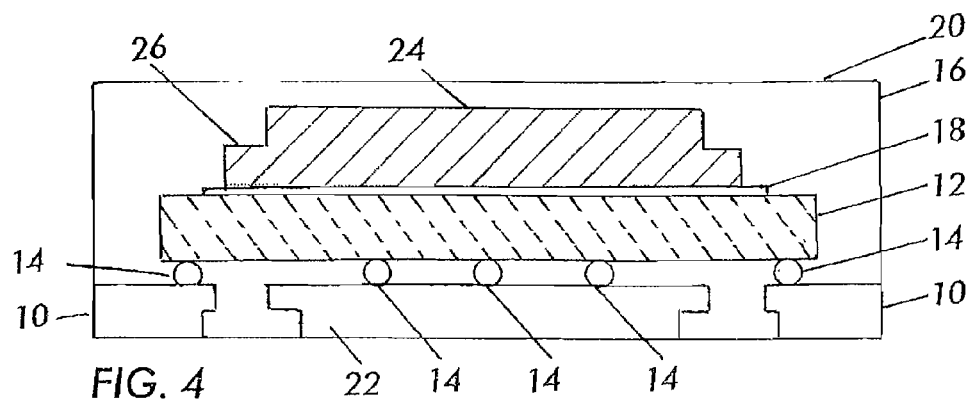
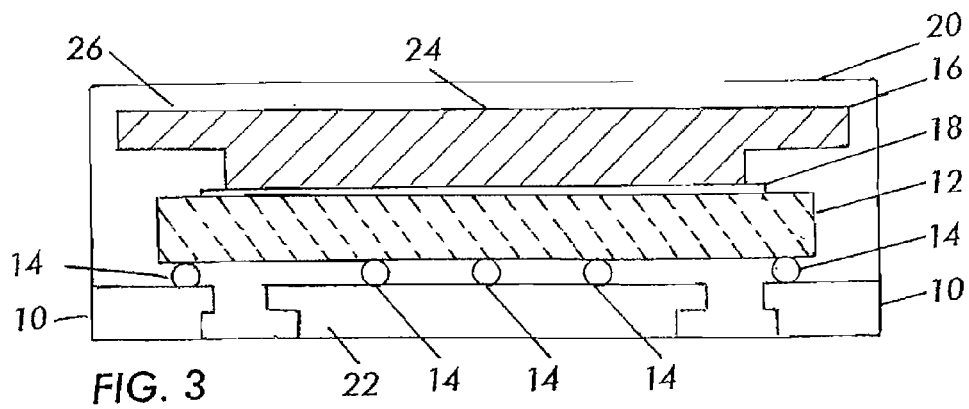
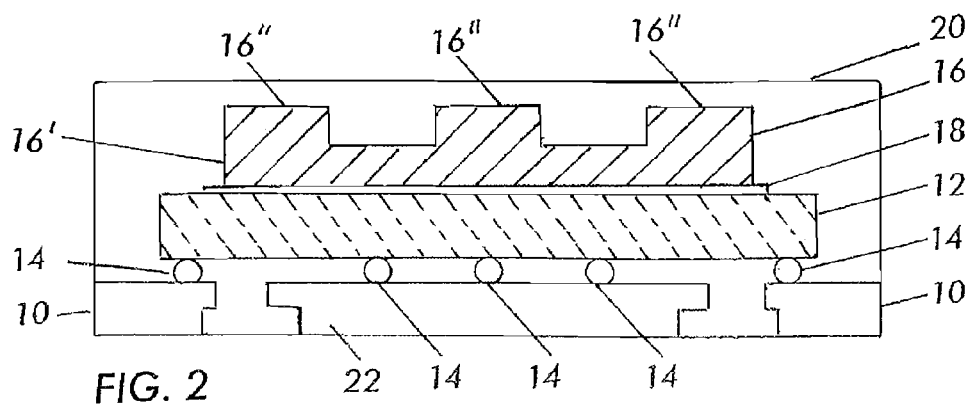
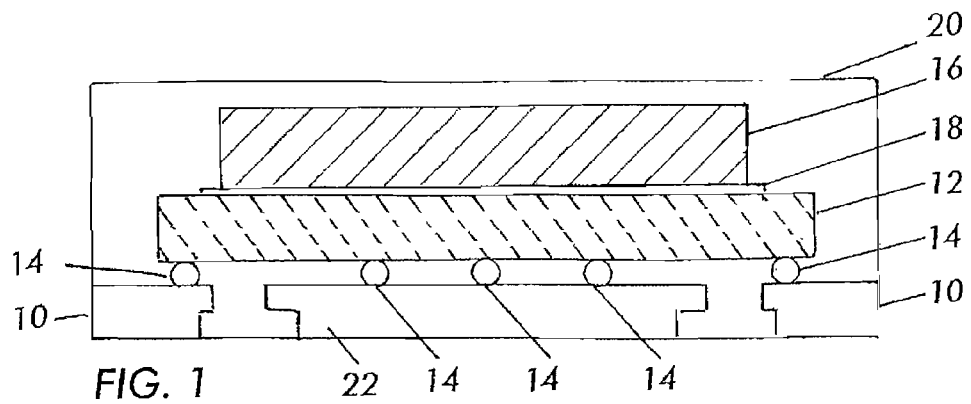
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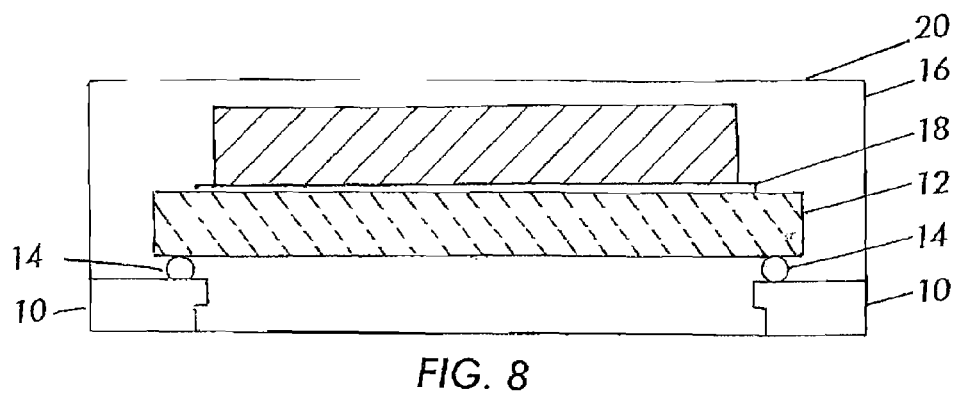
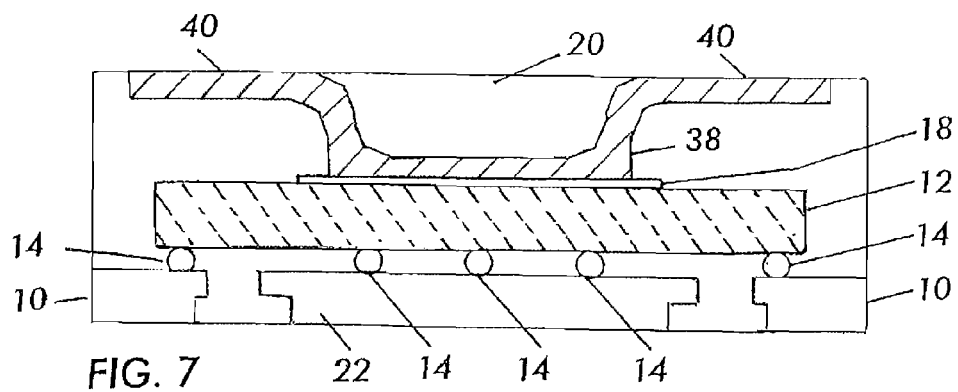
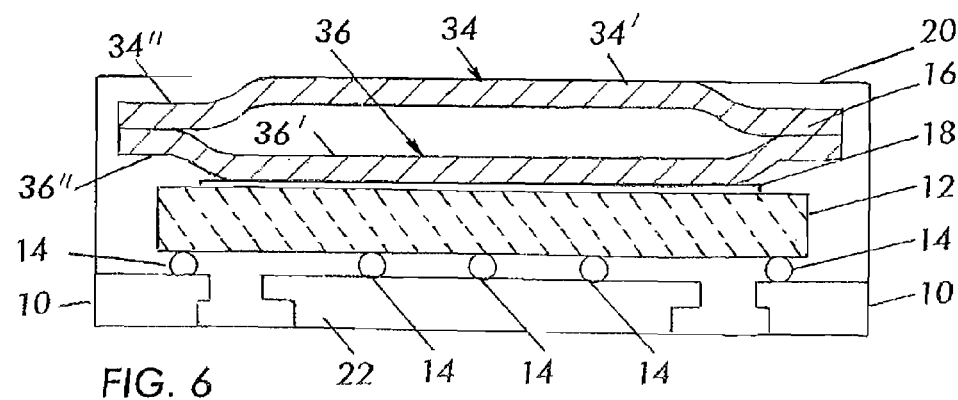
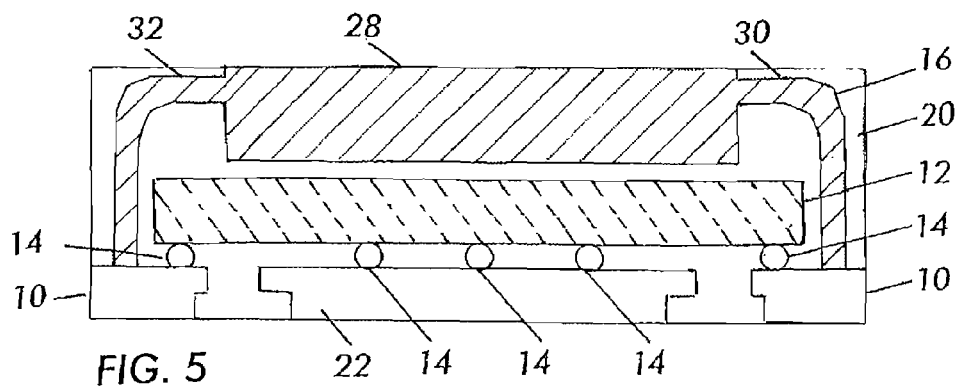
(57) **ABSTRACT**

A semiconductor package that includes a semiconductor die
and a heat spreader thermally coupled to the semiconductor
and disposed at least partially within the molded housing of
the package.

11 Claims, 2 Drawing Sheets







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SEMICONDUCTOR PACKAGE WITH CONDUCTIVE HEAT SPREADER

This is a divisional of application Ser. No. 11/715,226 filed Mar. 7, 2007.

RELATED APPLICATION

This application is based on and claims priority to the of U.S. Provisional Application Ser. No. 60/779,763, filed on Mar. 7, 2006, entitled Thermal Improvement on QFN Package, to which a claim of priority is hereby made and the disclosure of which is incorporated by reference.

BACKGROUND OF THE INVENTION

The present invention relates to semiconductor device packages.

A well known package arrangement is a Quad Flatpak No Lead (QFN) package. A QFN is a semiconductor package that includes a plurality of pads disposed at the edges thereof, and in some variations a die pad. The pads and the die pad are exposed at the bottom of the package and adapted for surface mounting.

It is well known that a semiconductor die within a package, such as a QFN package, generates heat while operating. The heat so generated must be dissipated to avoid adverse effects on the operation of the die.

One known method for dissipating the generated heat is to thermally connect a heat sink or a heat spreader to the outside of the package. Such a method, however, increases the height of the package. In addition, in such an arrangement the thermal path between the die and the heat sink or heat spreader includes the full thickness of the housing of the package, which prevents the efficient transfer of heat from the die to the heat dissipating body.

SUMMARY OF THE INVENTION

In a semiconductor package according to the present invention, a metallic heat spreader is disposed within the housing of a package and is mechanically and thermally connected to the die directly. Thus, the increase in the height of the package is avoided.

A semiconductor package according to the present invention includes a plurality of leads, a semiconductor die including a plurality of I/O electrodes on a first surface thereof, a conductive interconnect body interposed between each I/O electrode and a respective lead, a metallic heat spreader thermally and mechanically coupled to a second surface of the semiconductor die opposite the first surface, a molded housing encapsulating the semiconductor die, and the conductive interconnect bodies, and at least part of the metallic heat spreader.

According to one aspect of the present invention the metallic heat spreader is made from copper in order to absorb as much heat from the die as possible.

According to another aspect of the present invention solder or an electrically conductive polymer is used to couple the heat spreader to the inactive second surface of the semiconductor die in order to efficiently transfer heat from the die to the heat spreader.

Other features and advantages of the present invention will become apparent from the following description of the invention which refers to the accompanying drawings.

BRIEF DESCRIPTION OF THE DRAWING(S)

FIG. 1 shows a cross-sectional view of a package according to the first embodiment of the present invention.

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FIG. 2 shows a cross-sectional view of a package according to the second embodiment of the present invention.

FIG. 3 shows a cross-sectional view of a package according to the third embodiment of the present invention.

FIG. 4 shows a cross-sectional view of a package according to the fourth embodiment of the present invention.

FIG. 5 shows a cross-sectional view of a package according to the fifth embodiment of the present invention.

FIG. 6 shows a cross-sectional view of a package according to the sixth embodiment of the present invention.

FIG. 7 shows a cross-sectional view of a package according to the seventh embodiment of the present invention.

FIG. 8 shows a cross-sectional view of a package according to the eighth embodiment of the present invention.

DETAILED DESCRIPTION OF THE FIGURES

Referring to FIG. 1, a semiconductor package according to the first embodiment of the present invention includes a lead frame that includes a plurality of leads 10, a semiconductor die 12 that includes a plurality of input/output (I/O) electrodes (not shown specifically) on a first surface thereof, a conductive interconnect 14 interposed between each I/O electrode and a respective lead 10, a metallic heat spreader 16 thermally coupled to a second surface (opposite the first surface) of semiconductor die 12 with a thermally conductive adhesive body 18, and a molded housing 20 formed with mold compound molded over to encapsulate at least die 12, conductive interconnects 14, and at least portions of leads 10. Note that in the first embodiment, metallic heat spreader 16 is fully molded over by and thus encapsulated by molded housing 20. Furthermore, a package according to the first embodiment includes a die pad 22. Interconnects 14 are disposed between die pad 22 and first surface of die 12 whereby die 12 is further supported by die pad 22.

Preferably, interconnects 14 are solder bumps, but may be copper bumps, gold bumps, or pillar bumps. Further, preferably leads 10 are part of a QFN lead frame. Thus, a package according to the present invention preferably conforms to QFN standard. Moreover, because the second surface of die 12 is electrically inactive, solder or a conductive epoxy may be used (both efficient heat conductors) to couple heat spreader 16 to the second surface of die 12. It should be noted that a thermally conductive, but electrically non-conductive adhesive such as a thermal epoxy may be used as an adhesive body 18 without deviating from the present invention.

According to one aspect of the present invention, spreader 16 is formed with copper. Thus, in the first embodiment (FIG. 1) a copper block or slug is used as a heat spreader 16.

Referring now to FIG. 2, in which like numerals identify like features, in a package according to the second embodiment of the present invention, heat spreader 16, which may be formed with copper, includes a copper slug body 16' and a plurality of fins 16".

Referring to FIG. 3, in which like numerals identify like features, in a package according to the third embodiment heat spreader 16, which may be formed with copper, includes a first face 24 having a first lateral dimension and a second face 26 (opposite the first face 24) having a second lateral dimension that is wider than the first lateral dimension. In the third embodiment, first face 24 is coupled to the second surface of die 12.

In the fourth embodiment, as depicted by FIG. 4, second face 26 of heat spreader 16 is coupled to the second surface of die 12. Note that in a package according to the fourth embodiment first face 24 of heat spreader 16 is exposed through molded housing 20. To obtain an exposed first face 24 soft top

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molding may be employed. Alternatively, heat spreader **16** may be molded over with mold compound, and then exposed by grinding away the mold compound residing atop heat spreader **16**.

Referring now to FIG. **5**, in which like numerals identify like features, a package according to the fifth embodiment of the present invention includes a compressible (i.e. compliant) copper heat spreader, which includes a copper slug body **28** having at least a first leg **30**, and a second leg **32** each extending from a respective side of slug body **28**. Each leg **30**, **32** extends laterally outside the outer boundary of die **12** and includes an end that is disposed on a respective lead **10**, whereby heat spreader **16** is disposed over die **12** like a tent. Note that in a package according to the fifth embodiment instead of an adhesive, copper slug **28** may be coupled to die **12** through an interposing body of mold compound residing between slug **28** and the second surface of die **12**.

Referring now to FIG. **6**, in which like numerals identify like features, in a package according to the sixth embodiment, heat spreader **16** may be comprised of two saucer-shaped copper bodies **34**, **36** each including a cup portion **34'**, **36'** and a flange portion **34"**, **36"** disposed at the opening of the cup portion **34'**, **36'** thereof. Note that in the sixth embodiment the interiors of the cup portion **34'**, **36'** of saucer-shaped copper bodies **34**, **36** face one another, and flange portions **34"**, **36"** thereof are in contact with one another, whereby the arrangement is rendered compressible or compliant (as opposed to rigid).

Referring next to FIG. **7**, in which like numerals identify like features, in a package according to the seventh embodiment, heat spreader **16** is a compressible saucer-shaped copper body which includes a cup portion **38**, and a flange portion **40** at the opening of cup portion **38** thereof. Note that flange portion **40** is exposed through molded housing **20**.

Referring now to FIG. **8**, in which like numerals identify like features, in a package according to the eighth embodiment of the present invention, die pad **22** may be omitted, while other features of the invention may be retained. Thus, for example, as shown, a package according to the first embodiment may have die pad **22** thereof omitted to obtain a package according to the eighth embodiment.

Although the present invention has been described in relation to particular embodiments thereof, many other variations and modifications and other uses will become apparent to those skilled in the art. It is preferred, therefore, that the present invention be limited not by the specific disclosure herein, but only by the appended claims.

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What is claimed is:

1. A semiconductor package comprising:
 - a lead frame comprising a plurality of leads;
 - a semiconductor die that is supported by said lead frame and is electrically connected to said plurality of leads on a first surface of said semiconductor die;
 - a compressible heat spreader that is thermally and mechanically coupled to a second surface of said semiconductor die;
 - said compressible heat spreader comprising a cup portion that is thermally and mechanically coupled to said second surface of said semiconductor die, whereby an interior of said cup portion faces away from said semiconductor die, said compressible heat spreader not coupled to said lead frame.
2. The semiconductor package of claim 1, wherein said semiconductor die is supported by said plurality of leads and by a die pad of said lead frame.
3. The semiconductor package of claim 1, wherein said compressible heat spreader comprises a saucer-shaped conductive body.
4. The semiconductor package of claim 1, wherein said compressible heat spreader is isolated from said plurality of leads.
5. The semiconductor package of claim 1, wherein a molded housing encapsulates at least portions of said semiconductor die, said lead frame, and said compressible heat spreader.
6. A semiconductor package comprising:
 - a plurality of leads;
 - a semiconductor die electrically connected to said plurality of leads on a first surface of said semiconductor die;
 - a heat spreader comprising a cup portion that is thermally and mechanically coupled to a second surface of said semiconductor die, whereby an interior of said cup portion faces away from said semiconductor die, said heat spreader not coupled to said plurality of leads.
7. The semiconductor package of claim 6, wherein said heat spreader further comprises a flange disposed at an opening of said cup portion.
8. The semiconductor package of claim 6, wherein said heat spreader further comprises a flange extending from and disposed around an opening of said cup portion.
9. The semiconductor package of claim 6, wherein said heat spreader is isolated from said plurality of leads.
10. The semiconductor package of claim 6, wherein said plurality of leads are of a lead frame.
11. The semiconductor package of claim 6, wherein said surface of said die is electrically inactive.

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